

ISL9K1560G3

15A, 600V Stealth™ Dual Diode

General Description

The ISL9K1560G3 is a StealthTM dual diode optimized for low loss performance in high frequency hard switched applications. The StealthTM family exhibits low reverse recovery current ($I_{RM(REC)}$) and exceptionally soft recovery under typical operating conditions.

This device is intended for use as a free wheeling or boost diode in power supplies and other power switching applications. The low $I_{RM(REC)}$ and short t_a phase reduce loss in switching transistors. The soft recovery minimizes ringing, expanding the range of conditions under which the diode may be operated without the use of additional snubber circuitry. Consider using the Stealth $^{\rm TM}$ diode with an SMPS IGBT to provide the most efficient and highest power density design at lower cost.

Formerly developmental type TA49410.

Features

•	Soft Recovery $t_b/t_a > 1.2$
•	Fast Recovery t_{rr} < 30ns
•	Operating Temperature
•	Reverse Voltage

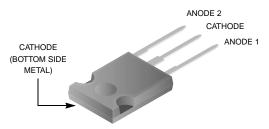
Avalanche Energy Rated

Applications

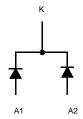
- · Switch Mode Power Supplies
- · Hard Switched PFC Boost Diode
- · UPS Free Wheeling Diode
- · Motor Drive FWD
- SMPS FWD
- · Snubber Diode

Package

JEDEC STYLE TO-247



Symbol



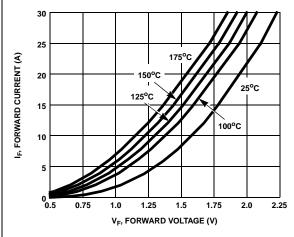
Device Maximum Ratings (per leg) T_C = 25°C unless otherwise noted

Symbol	Parameter	Ratings	Units
V_{RRM}	Repetitive Peak Reverse Voltage	600	V
V_{RWM}	Working Peak Reverse Voltage	600	V
V _R	DC Blocking Voltage	600	V
I _{F(AV)}	Average Rectified Forward Current (T _C = 145°C) Total Device Current (Both Legs)	15 30	A A
I _{FRM}	Repetitive Peak Surge Current (20kHz Square Wave)	30	Α
I _{FSM}	Nonrepetitive Peak Surge Current (Halfwave 1 Phase 60Hz)	200	Α
P _D	Power Dissipation	150	W
E _{AVL}	Avalanche Energy (1A, 40mH)	20	mJ
T _J , T _{STG}	Operating and Storage Temperature Range	-55 to 175	°C
T _L T _{PKG}	Maximum Temperature for Soldering Leads at 0.063in (1.6mm) from Case for 10s Package Body for 10s, See Techbrief TB334	300 260	°C

CAUTION: Stresses above those listed in "Device Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.

Device Marking Device		Package	Tape Width			Quantity		
K1560G3		ISL9K1560G3	TO-247	N/A			30	
Electric	cal Char	acteristics (per leg)	T _C = 25°C unles	ss otherwise noted				
Symbol	Parameter		Test Conditions		Min	Тур	Max	Units
Off State	Charact	eristics				•		
I _R	Instantaneous Reverse Current		V _R = 600V	T _C = 25°C	-	-	100	μА
				T _C = 125°C	-	-	1.0	mA
On State	Charact	eristics						
V _F	Instantaneous Forward Voltage		I _F = 15A	T _C = 25°C	-	1.8	2.2	V
		· ·	'	T _C = 125°C	-	1.65	2.0	V
	Charact		T.			1	T	1
C_J	Junction C	apacitance	$V_{R} = 10V, I_{F} = 0A$		-	62	-	pF
Switchin	Reverse R	ecovery Time	$I_F = 1A$, $dI_F/dt =$	= 100A/μs, V _R = 30V	-	25	30	ns
	,		$I_F = 15A$, $dI_F/dt = 100A/\mu s$, $V_R = 30V$		-	35	40	ns
t _{rr}	Reverse R	Reverse Recovery Time $I_F = 15A$,						
		ecovery Time			ı	29.4	-	ns
I _{RM(REC)}		Reverse Recovery Current	dI _F /dt = 200A/μ		1 1	29.4 3.5	-	ns A
I _{RM(REC)} Q _{RR}	Maximum		$dI_F/dt = 200A/\mu s$ $V_R = 390V, T_C = 100$					
	Maximum Reverse R Reverse R	Reverse Recovery Current ecovered Charge ecovery Time	$dI_{F}/dt = 200A/\mu s$ $V_{R} = 390V, T_{C} = I_{F} = 15A,$	= 25°C	-	3.5	-	Α
Q _{RR}	Maximum Reverse R Reverse R Softness F	Reverse Recovery Current ecovered Charge ecovery Time factor (t _b /t _a)	$\begin{aligned} & dI_{F}/dt = 200A/\mu s \\ & V_{R} = 390V, T_{C} = \\ & I_{F} = 15A, \\ & dI_{F}/dt = 200A/\mu s \end{aligned}$	= 25°C	-	3.5 57	-	A nC
Q _{RR}	Maximum Reverse R Reverse R Softness F Maximum	Reverse Recovery Current ecovered Charge ecovery Time factor (t _b /t _a) Reverse Recovery Current	$\begin{aligned} &\text{dI}_{\text{F}}/\text{dt} = 200\text{A}/\mu\text{s} \\ &\text{V}_{\text{R}} = 390\text{V}, \text{T}_{\text{C}} = \\ &\text{I}_{\text{F}} = 15\text{A}, \\ &\text{dI}_{\text{F}}/\text{dt} = 200\text{A}/\mu\text{s} \\ &\text{V}_{\text{R}} = 390\text{V}, \end{aligned}$	= 25°C	-	3.5 57 90 2.0 5.0		A nC ns
$\begin{array}{c} Q_{RR} \\ t_{rr} \\ S \\ I_{RM(REC)} \\ Q_{RR} \end{array}$	Maximum Reverse R Reverse R Softness F Maximum Reverse R	Reverse Recovery Current ecovered Charge ecovery Time factor (t _b /t _a) Reverse Recovery Current ecovered Charge	$\begin{aligned} &\text{dI}_{\text{F}}/\text{dt} = 200\text{A}/\mu\text{s} \\ &\text{V}_{\text{R}} = 390\text{V}, \text{ T}_{\text{C}} = \\ &\text{I}_{\text{F}} = 15\text{A}, \\ &\text{dI}_{\text{F}}/\text{dt} = 200\text{A}/\mu\text{s} \\ &\text{V}_{\text{R}} = 390\text{V}, \\ &\text{-T}_{\text{C}} = 125^{\circ}\text{C} \end{aligned}$	= 25°C		3.5 57 90 2.0 5.0 275	- - -	A nC ns
$\begin{array}{c} Q_{RR} \\ t_{rr} \\ S \\ I_{RM(REC)} \\ Q_{RR} \\ t_{rr} \end{array}$	Maximum Reverse R Reverse R Softness F Maximum Reverse R Reverse R	Reverse Recovery Current ecovered Charge ecovery Time factor (t _b /t _a) Reverse Recovery Current ecovered Charge ecovery Time	$\begin{array}{l} dI_F/dt = 200A/\mu \\ V_R = 390V, \ T_C = \\ I_F = 15A, \\ dI_F/dt = 200A/\mu \\ V_R = 390V, \\ T_C = 125^{\circ}C \\ \\ I_F = 15A, \end{array}$	= 25°C s,	- - - -	3.5 57 90 2.0 5.0 275 52	- - -	A nC ns
$\begin{array}{c} Q_{RR} \\ t_{rr} \\ S \\ \\ I_{RM(REC)} \\ Q_{RR} \\ t_{rr} \\ S \\ \end{array}$	Maximum Reverse R Reverse R Softness F Maximum Reverse R Reverse R Softness F	Reverse Recovery Current ecovered Charge ecovery Time factor (t _b /t _a) Reverse Recovery Current ecovered Charge ecovery Time factor (t _b /t _a)	$\begin{aligned} &\text{dI}_F/\text{dt} = 200\text{A}/\mu\text{s} \\ &\text{V}_R = 390\text{V}, \text{ T}_C = \\ &\text{I}_F = 15\text{A}, \\ &\text{dI}_F/\text{dt} = 200\text{A}/\mu\text{s} \\ &\text{V}_R = 390\text{V}, \\ &\text{T}_C = 125^\circ\text{C} \\ &\text{I}_F = 15\text{A}, \\ &\text{dI}_F/\text{dt} = 800\text{A}/\mu\text{s} \end{aligned}$	= 25°C s,	- - - - - -	3.5 57 90 2.0 5.0 275 52 1.36	- - -	A nC ns A nC ns
$\begin{array}{c} Q_{RR} \\ t_{rr} \\ S \\ \\ l_{RM(REC)} \\ Q_{RR} \\ t_{rr} \\ S \\ \\ l_{RM(REC)} \end{array}$	Maximum Reverse R Reverse R Softness F Maximum Reverse R Reverse R Softness F Maximum	Reverse Recovery Current ecovered Charge ecovery Time factor (t _b /t _a) Reverse Recovery Current ecovered Charge ecovery Time factor (t _b /t _a) Reverse Recovery Current	$\begin{array}{l} dI_F/dt = 200A/\mu \\ V_R = 390V, \ T_C = \\ I_F = 15A, \\ dI_F/dt = 200A/\mu \\ V_R = 390V, \\ T_C = 125^{\circ}C \\ \\ I_F = 15A, \end{array}$	= 25°C s,	- - - - - -	3.5 57 90 2.0 5.0 275 52 1.36 13.5	- - -	A nC ns A nC ns
$\begin{array}{c} Q_{RR} \\ t_{rr} \\ S \\ \\ I_{RM(REC)} \\ Q_{RR} \\ t_{rr} \\ S \\ \\ I_{RM(REC)} \\ Q_{RR} \end{array}$	Maximum Reverse R Reverse R Softness F Maximum Reverse R Reverse R Softness F Maximum Reverse R	Reverse Recovery Current ecovered Charge ecovery Time factor (t _b /t _a) Reverse Recovery Current ecovered Charge ecovery Time factor (t _b /t _a) Reverse Recovery Current ecovered Charge	$\begin{array}{l} \text{dI}_{\text{F}}/\text{dt} = 200\text{A}/\mu\text{s} \\ \text{V}_{\text{R}} = 390\text{V}, \text{ T}_{\text{C}} = \\ \text{I}_{\text{F}} = 15\text{A}, \\ \text{dI}_{\text{F}}/\text{dt} = 200\text{A}/\mu\text{s} \\ \text{V}_{\text{R}} = 390\text{V}, \\ \text{T}_{\text{C}} = 125^{\circ}\text{C} \\ \text{I}_{\text{F}} = 15\text{A}, \\ \text{dI}_{\text{F}}/\text{dt} = 800\text{A}/\mu\text{s} \\ \text{V}_{\text{R}} = 390\text{V}, \end{array}$	= 25°C s,	- - - - - -	3.5 57 90 2.0 5.0 275 52 1.36 13.5 390	- - -	A nC ns A nC ns
$\begin{array}{c} Q_{RR} \\ t_{rr} \\ S \\ \\ l_{RM(REC)} \\ Q_{RR} \\ t_{rr} \\ S \\ \\ l_{RM(REC)} \end{array}$	Maximum Reverse R Reverse R Softness F Maximum Reverse R Reverse R Softness F Maximum Reverse R	Reverse Recovery Current ecovered Charge ecovery Time factor (t _b /t _a) Reverse Recovery Current ecovered Charge ecovery Time factor (t _b /t _a) Reverse Recovery Current	$\begin{array}{l} \text{dI}_{\text{F}}/\text{dt} = 200\text{A}/\mu\text{s} \\ \text{V}_{\text{R}} = 390\text{V}, \text{ T}_{\text{C}} = \\ \text{I}_{\text{F}} = 15\text{A}, \\ \text{dI}_{\text{F}}/\text{dt} = 200\text{A}/\mu\text{s} \\ \text{V}_{\text{R}} = 390\text{V}, \\ \text{T}_{\text{C}} = 125^{\circ}\text{C} \\ \text{I}_{\text{F}} = 15\text{A}, \\ \text{dI}_{\text{F}}/\text{dt} = 800\text{A}/\mu\text{s} \\ \text{V}_{\text{R}} = 390\text{V}, \end{array}$	= 25°C s,	- - - - - -	3.5 57 90 2.0 5.0 275 52 1.36 13.5	- - -	A nC ns A nC ns
$\begin{array}{c} Q_{RR} \\ t_{rr} \\ S \\ \\ I_{RM(REC)} \\ Q_{RR} \\ t_{rr} \\ S \\ \\ I_{RM(REC)} \\ Q_{RR} \\ dI_{M}/dt \\ \end{array}$	Maximum Reverse R Reverse R Softness F Maximum Reverse R Reverse R Softness F Maximum Reverse R	Reverse Recovery Current ecovered Charge ecovery Time factor (t _b /t _a) Reverse Recovery Current ecovered Charge ecovery Time factor (t _b /t _a) Reverse Recovery Current ecovered Charge ecovery Time factor (t _b /t _a) Reverse Recovery Current ecovered Charge di/dt during t _b	$\begin{array}{l} \text{dI}_{\text{F}}/\text{dt} = 200\text{A}/\mu\text{s} \\ \text{V}_{\text{R}} = 390\text{V}, \text{ T}_{\text{C}} = \\ \text{I}_{\text{F}} = 15\text{A}, \\ \text{dI}_{\text{F}}/\text{dt} = 200\text{A}/\mu\text{s} \\ \text{V}_{\text{R}} = 390\text{V}, \\ \text{T}_{\text{C}} = 125^{\circ}\text{C} \\ \text{I}_{\text{F}} = 15\text{A}, \\ \text{dI}_{\text{F}}/\text{dt} = 800\text{A}/\mu\text{s} \\ \text{V}_{\text{R}} = 390\text{V}, \end{array}$	= 25°C s,	- - - - - -	3.5 57 90 2.0 5.0 275 52 1.36 13.5 390	- - -	A nC ns A nC ns
$\begin{array}{c} Q_{RR} \\ t_{rr} \\ S \\ \\ I_{RM(REC)} \\ Q_{RR} \\ t_{rr} \\ S \\ \\ I_{RM(REC)} \\ Q_{RR} \\ dI_{M}/dt \\ \end{array}$	Maximum Reverse R Reverse R Softness F Maximum Reverse R Reverse R Softness F Maximum Reverse R Maximum Reverse R	Reverse Recovery Current ecovered Charge ecovery Time factor (t _b /t _a) Reverse Recovery Current ecovered Charge ecovery Time factor (t _b /t _a) Reverse Recovery Current ecovered Charge ecovery Time factor (t _b /t _a) Reverse Recovery Current ecovered Charge di/dt during t _b	$\begin{array}{l} \text{dI}_{\text{F}}/\text{dt} = 200\text{A}/\mu\text{s} \\ \text{V}_{\text{R}} = 390\text{V}, \text{ T}_{\text{C}} = \\ \text{I}_{\text{F}} = 15\text{A}, \\ \text{dI}_{\text{F}}/\text{dt} = 200\text{A}/\mu\text{s} \\ \text{V}_{\text{R}} = 390\text{V}, \\ \text{T}_{\text{C}} = 125^{\circ}\text{C} \\ \text{I}_{\text{F}} = 15\text{A}, \\ \text{dI}_{\text{F}}/\text{dt} = 800\text{A}/\mu\text{s} \\ \text{V}_{\text{R}} = 390\text{V}, \end{array}$	= 25°C s,	- - - - - -	3.5 57 90 2.0 5.0 275 52 1.36 13.5 390	- - -	A nC ns A nC ns

Typical Performance Curves



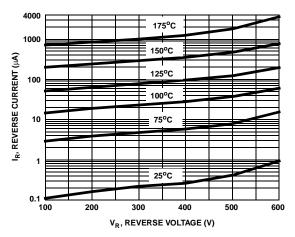
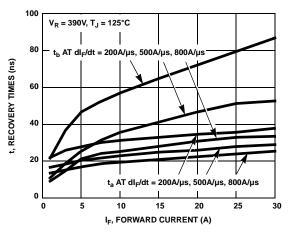


Figure 1. Forward Current vs Forward Voltage

Figure 2. Reverse Current vs Reverse Voltage



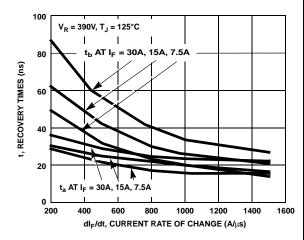
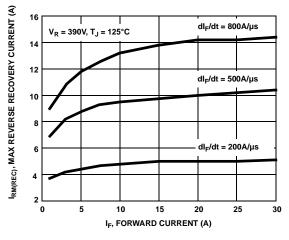


Figure 3. t_a and t_b Curves vs Forward Current

Figure 4. t_a and t_b Curves vs dl_F/dt



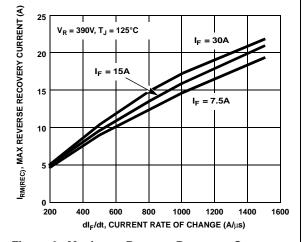
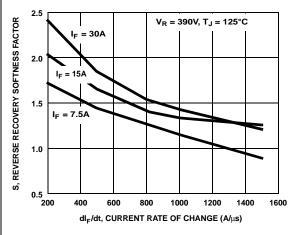


Figure 5. Maximum Reverse Recovery Current vs Forward Current

Figure 6. Maximum Reverse Recovery Current vs dl_F/dt

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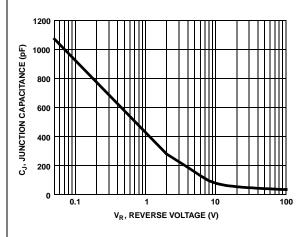
Typical Performance Curves (Continued)



700 V_R = 390V, T_J = 125°C I_F = 30A I_F = 15A V_R = 390V, T_J = 125°C I_F = 30A I_F = 15A V_R = 300 V_R = 390V, T_J = 125°C V_R = 30A V_R

Figure 7. Reverse Recovery Softness Factor vs dI_F/dt

Figure 8. Reverse Recovered Charge vs $\mathrm{dI}_{\mathrm{F}}/\mathrm{dt}$



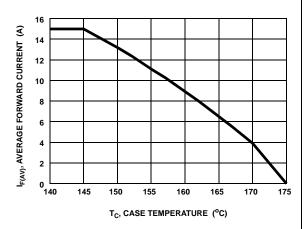


Figure 9. Junction Capacitance vs Reverse Voltage

Figure 10. DC Current Derating Curve

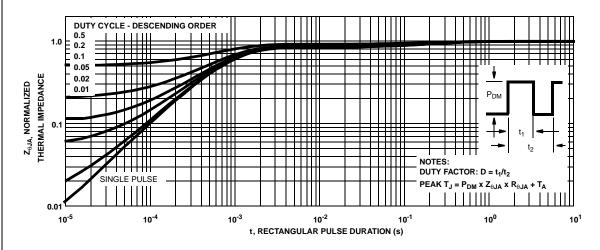
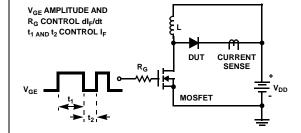


Figure 11. Normalized Maximum Transient Thermal Impedance

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Test Circuit and Waveforms



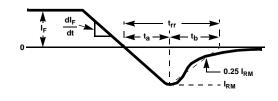


Figure 12. t_{rr} Test Circuit

Figure 13. t_{rr} Waveforms and Definitions

I = 1A L = 40mH $R < 0.1\Omega$ $V_{DD} = 50V$ $E_{AVL} = 1/2LI^2 \left[V_{R(AVL)} / (V_{R(AVL)} - V_{DD}) \right]$ $Q_1 = IGBT \left(BV_{CES} > DUT \ V_{R(AVL)} \right)$ CURRENT + 0 $SENSE V_{DD}$ V_{DD} V_{DD}

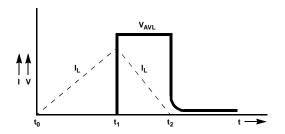


Figure 14. Avalanche Energy Test Circuit

Figure 15. Avalanche Current and Voltage Waveforms

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CROSSVOLT™	FRFET™	MicroPak™	QFET™	SuperSOT™-8
DOME™	GlobalOptoisolator™	MICROWIRE™	QS™	SyncFET™
EcoSPARK™	GTO™	MSX™	QT Optoelectronics™	TinyLogic™
E ² CMOS™	HiSeC™	MSXPro™	Quiet Series™	TruTranslation™
EnSigna™	I ² C™	OCX TM	RapidConfigure™	UHC™
Across the board	. Around the world.™	OCXPro™	RapidConnect™	UltraFET [®]
The Power Franc	hise™	OPTOLOGIC®	SILENT SWITCHER®	VCX™
Programmable Ad	ctive Droop™	OPTOPLANAR™	SMART START™	

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PRODUCT STATUS DEFINITIONS

Definition of Terms

Datasheet Identification	Product Status	Definition
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No Identification Needed	Full Production	This datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice in order to improve design.
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